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## Research Center of Laser Fusion Chinese Academy of Engineering Physics







## Introduction



## Design and performances of a R-PEPC

## **Summary**





## Introduction

Story of steps towards HEC-RF requirements

Design and performances of a R-PEPC

## Summary





- Merits of multi-pass amplifying scheme have been validated in respect of high extraction efficiency, cost saving, and physical size reducing
- In this amplifier, an optical switch is required for laser pulse injecting, ejecting, and parasitic oscillation suppressing
- As for high energy, repetition rate operating, large laser facility

	Parameter	Performance
	clear aperture	multi-cm to tens of cm
	damage threshold	mulit-J/cm <sup>2</sup>
whilet 3	temporal response	nanoseconds-scale
	average power intensity	tens W/cm <sup>2</sup>
Ŭ,	repetition rate	around 10 Hz



Meeting the required aperture size, damage threshold, temporal response Using thin EO crystal while keeping switching voltage at a low level

Make it appropriate for HEC-rf operation

For LMJ in CEA

### For SG-III in RCLF







# Introduction Story of steps towards HEC-RF requirements Design and performances of a R-PEPC Summary

## **Briefly Introducing the concept of PEPC**



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## Schematic of the PEPC architecture









Single pulse driven (SPD)





- Without high-current pre-ionization process
  - The gas discharge time is shortened from tens of ms to hundreds of ns.
  - Spotting optical elements, due to cathode sputtering, is reduced.
  - The heat deposition in crystal, heated by cathodes, is reduced.
- The SPD mode is more suitable for rf application.

## Drawbacks of SPD for HEC-RF application







- ♦ KDP, DKDP is only available EO crystal which meets requirement of large-dimensions.
- ♦ DKDP, with a lower absorption coefficient (~0.2%cm<sup>-1</sup>) than that of KDP (5%cm<sup>-1</sup>), is the best choice at present.

Drawbacks of SPD for HEC-RF application

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## However,

- ◆ The needed voltage to breakdown the gas ≥12 kV, so SPD PEPC generally uses KDP as electro-optic crystal because of its high half-wave voltage.
- The half-wave voltage of DKDP is ~6.8 kV, that is too low to realize single pulse driven PEPC.





- A dividing capacitor is arranged in the circuit.
- Appropriate  $C_o$  and U makes that SPD DKDP PEPC works.

A single pulse driven DKDP PEPC Research Center of Laser Fusion CAEP



- ◆ A PEPC is fabricated to examine this scheme
- $\bullet \sim 10^5$  shots operating shows no degrading of transmission rate.
- Neither depolarization loss is observed in 2h continuous operating.

	Parameter	Performance
	Clear aperture: $\varphi$ 30mm	Rising time: 9.8ns
	DKDP thickness: 3mm	Rep. rate: 10Hz
	Driving voltage: <15kV	Insertion loss: 98.6%
	Extinction ratio: >10 <sup>3</sup> : 1	Switching efficiency: ~99.5%

# Thermo-effects arising from DKDP absorption of laser



- Even though DKDP has a lower absorption coefficient, thermo-effects is remarkable.
- Optical switch is sensitive to thermo induced birefringence.
- The deposited heat must be removed in time.

# Heat convection coefficient of operating gas







- Optimizing gas-flow distribution and heat convection coefficient by CFD
- Unfortunately, low operating pressure results in a  $h_c$  of ~10<sup>-4</sup> W/cm<sup>2</sup>K.
- This  $h_c$  is too small to efficiently remove the deposited heat in crystal.

Quantitatively describing of thermo-effects Research Center of Laser Fusion CAEP



Supposing the laser average power intensity is 30 W/cm<sup>2</sup>



## Demonstrating of the reflective PEPC concept

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### **DKDP** is longitudinally cooled

- Short heat-flux path-length
- large heat transfer area
- High cooling efficiency
- Small transverse temperature gradients









"Cold" performances not changing		
Parameter	Performance	
clear aperture	40mm×40mm	
Extinction ratio	~1000:1	
Switching efficiency	99.6%	
Driving voltage	12.5 kV	
Rising time	11 ns	
Shot-to-shot jitter	10 ns (mainly from driver)	

Thermal resistivity between DKDP and heat sink Research Center of Laser Fusion CAEP

- Heating source: 980 nm laser, 50 W/cm<sup>2</sup>, beam aperture  $\Phi$ 20mm
- ◆ Measured thermal resistivity: around 65 cm<sup>2</sup>K/W









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## **Design of a R-PEPC for 100J/10Hz amplifier**

Si Mirror

Housing body

**M** Research Center of Laser Fusion CAEP

## Output fluence is 5 J/cm<sup>2</sup> For 100 J/10 Hz application Clear aperture: 45mm×45mm

- ◆ DKDP: 55mm×55mm×6mm
- ♦ Si Mirror: Φ80mm×8mm
- ◆ Matching impedance: 12.5 ohm
- ♦ Plasma Chamber: Φ80mm×8mm



Window

- ◆ Insertion loss: 1.5%
- ♦ theory rising time: 2.5 ns

Gas channel

• Driving voltage: 15.5 kV





- At thermal steady-state, max temperature rise in DKDP is 2.5
   °C, whereas temperature difference is 0.6 °C
- There is a temperature drop of 1.8 °C between DKDP and Simirror contact surfaces due to contact thermal resistivity.

## Depolarization & wavefront distortion



- ◆ Maximal depolarization: 0.22%, located at corners of the laser beam
- Average depolarization: 0.02%, over the laser beam
- Wavefront distortion: 0.18  $\lambda$  ( $\lambda$ =1030 nm)





# Introduction

**Story of steps towards HEC-RF requirements** 

## Design and performances of a R-PEPC

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- We introduce challenges that PEPC encounters for HEC-rf application
  - One single pulse driven DKDP PEPC
  - Thermo-effects
- and their tactics are demonstrated.
  - Capacitance dividing voltage method
  - Reflective design and conduction-cooling
- ♦ At last, we present the design of a R-PEPC for 100J/10Hz amplifier application, and its performances are discussed.

